## **Power Transistors**

## Panasonic

# 2SB0938 (2SB938), 2SB0938A (2SB938A)

Silicon PNP epitaxial planar type darlington

For power amplification and switching

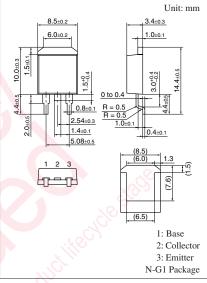
Complementary to 2SD1261, 2SD1261A

#### Features

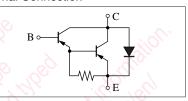
- $\bullet$  High forward current transfer ratio  $h_{FE}$
- High-speed switching
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

#### Absolute Maximum Ratings $T_C = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB0938	V <sub>CBO</sub>	-60	V
(Emitter open)	2SB0938A		-80	
Collector-emitter voltage	2SB0938	V <sub>CEO</sub>	-60	V
(Base open)	2SB0938A		-80	
Emitter-base voltage (Collector open)		V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-4	A	
Peak collector current	I <sub>CP</sub>	-8	А	
Collector power dissipation		P <sub>C</sub>	40	W
	$T_a = 25^{\circ}C$		1.3	
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to +150	C.



Note) Self-supported type package is also prepared. Internal Connection



### Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

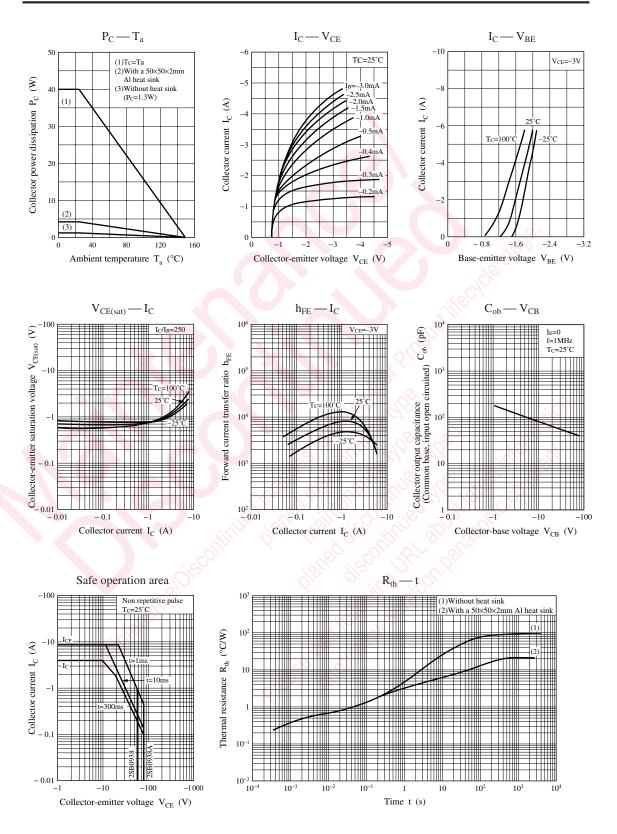
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage2SB0938(Base open)2SB0938A		V <sub>CEO</sub>	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-60	, o C		V
		S		-80	00		
Base-emitter voltage		V <sub>BE</sub>	$V_{CE} = -3 V, I_C = -3 A$		5	-2.5	V
Collector-base cutoff	2SB0938	I <sub>CBO</sub>	$V_{CB} = -60 \text{ V}, I_E = 0$	00		-200	μΑ
current (Emitter open)	2SB0938A		$V_{CB} = -80 \text{ V}, I_E = 0$			-200	
Collector-emitter cutoff	2SB0938	I <sub>CEO</sub>	$V_{CE} = -30 \text{ V}, I_B = 0$			-500	μΑ
current (Base open)	2SB0938A		$V_{CE} = -40 \text{ V}, I_B = 0$			-500	
Emitter-base cutoff current (Collector open)		I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$			-2	mA
		h <sub>FE1</sub>	$V_{CE} = -3 V, I_C = -0.5 A$	1 0 0 0			
		h <sub>FE2</sub> *	$V_{CE} = -3 V, I_C = -3 A$	2 0 0 0		10 000	
Collector-emitter saturation voltage V <sub>CE0</sub>		V <sub>CE(sat)</sub>	$I_{C} = -3 \text{ A}, I_{B} = -12 \text{ mA}$			-2	V
			$I_{\rm C} = -5$ A, $I_{\rm B} = -20$ mA			-4	
Transition frequency		f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 1 \text{ MHz}$		15		MH
Turn-on time		t <sub>on</sub>	$I_{\rm C} = -3$ A,		0.3		μs
Storage time		t <sub>stg</sub>	$I_{B1} = -12 \text{ mA}, I_{B2} = 12 \text{ mA}$		2		μs
Fall time		t <sub>f</sub>	$V_{\rm CC} = -50  \rm V$		0.5		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. \*: Rank classification

 Rank
 Q
 P

 h<sub>FE1</sub>
 2 000 to 5 000
 4 000 to 10 000
 Note) The part number in the parenthesis shows conventional part number.

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